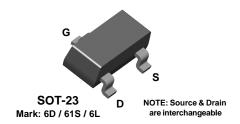


2N5457 2N5458 2N5459

**MMBF5457 MMBF5458 MMBF5459** 





# **N-Channel General Purpose Amplifier**

This device is a low level audio amplifier and switching transistors, and can be used for analog switching applications. Sourced from Process 55.

#### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{DG}$	Drain-Gate Voltage	25	V
V <sub>GS</sub>	Gate-Source Voltage	- 25	V
I <sub>GF</sub>	Forward Gate Current	10	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

# Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	N	Max	
		2N5457-5459	*MMBF5457-5459	
$P_D$	Total Device Dissipation	625	350	mW
	Derate above 25°C	5.0	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

<sup>1)</sup> These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# **N-Channel General Purpose Amplifier**

(continued)

	ectrical Characteri

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units

## **OFF CHARACTERISTICS**

V <sub>(BR)GSS</sub>	Gate-Source Breakdown Voltage	$I_G = 10 \mu A, V_{DS} = 0$		- 25			V
I <sub>GSS</sub>	Gate Reverse Current	$V_{GS} = -15 \text{ V}, V_{DS} = 0$ $V_{GS} = -15 \text{ V}, V_{DS} = 0, T_{A} = 0$	100°C			- 1.0 - 200	nA nA
V <sub>GS(off)</sub>	Gate-Source Cutoff Voltage	$V_{DS} = 15 \text{ V}, V_{DS} = 0, T_{A} = 0$ $V_{DS} = 15 \text{ V}, I_{D} = 10 \text{ nA}$	5457 5458	- 0.5 - 1.0		- 6.0 - 7.0	V
V <sub>GS</sub>	Gate-Source Voltage	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 100 μA V <sub>DS</sub> = 15 V, I <sub>D</sub> = 200 μA V <sub>DS</sub> = 15 V, I <sub>D</sub> = 400 μA	5459 5457 5458 5459	- 2.0	- 2.5 - 3.5 - 4.5	- 8.0	V V V

## **ON CHARACTERISTICS**

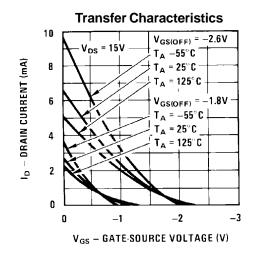
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current*	$V_{DS} = 15 \text{ V}, V_{GS} = 0$	5457	1.0	3.0	5.0	mΑ
			5458	2.0	6.0	9.0	mΑ
			5459	4.0	9.0	16	mΑ

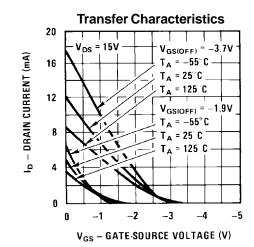
## SMALL SIGNAL CHARACTERISTICS

9 <sub>fs</sub>	Forward Transfer Conductance*	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$				
		5457 5458 5459	1000 1500 2000		5000 5500 6000	μmhos μmhos μmhos
gos	Output Conductance*	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$		10	50	μmhos
Ciss	Input Capacitance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 MHz		4.5	7.0	pF
Crss	Reverse Transfer Capacitance	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ MHz}$		1.5	3.0	pF
NF	Noise Figure	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}, R_G = 1.0 \text{ megohm}, BW = 1.0 \text{ Hz}$			3.0	dB

<sup>\*</sup>Pulse Test: Pulse Width ≤ 300 ms, Duty Cycle ≤ 2%

# **Typical Characteristics**

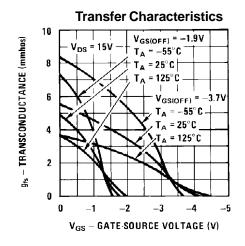


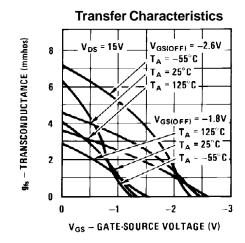


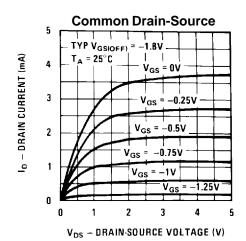
## **N-Channel General Purpose Amplifier**

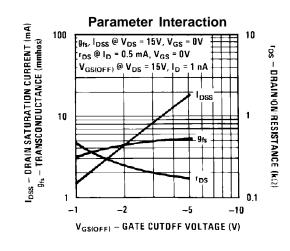
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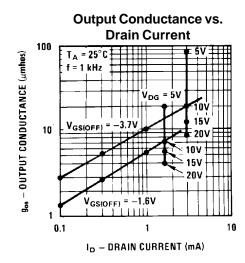
## Typical Characteristics (continued)

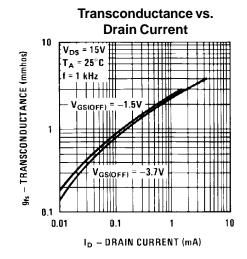








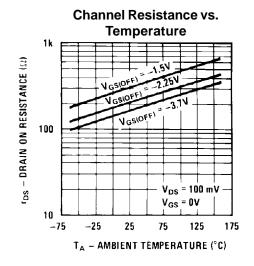


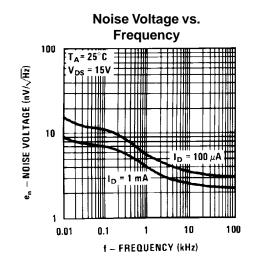


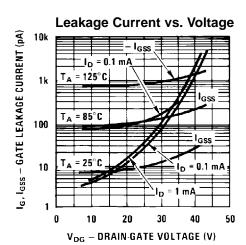
## **N-Channel General Purpose Amplifier**

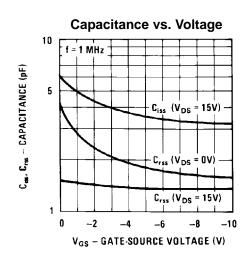
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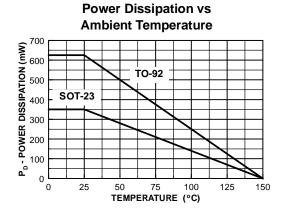
# Typical Characteristics (continued)











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